

14701 Firestone Blvd \* La Mirada, Ca 90638 Phone: (562) 404-4474 \* Fax: (562) 404-1773 ssdi@ssdi-power.com \* www.ssdi-power.com

# **Designer's Data Sheet**

## Part Number/Ordering Information $\frac{1}{2}$

SD 01 40

<sup>L</sup> Screening <sup>2/</sup> = Not Screened  $\overline{TX} = TX$  Level TXV = TXV Level S = S Level

### Package Type SO8 = 8 Pin SOIC SO16 = 16 Pin SOIC

# **SD0140**

# **1 AMP, 400 VOLTS** SCHOTTKY DIODE ARRAY

# FEATURES:

- An array of 4 or 8 diodes each leg has 2 • diodes in series for redundancy
- High reliability hermetic ceramic packages •
- Low capacitance
- Low leakage •
- TX, TXV, and S level screening available consult factory

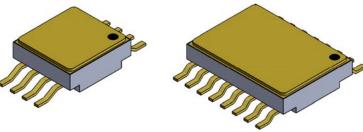
MAXIMUM RATINGS <sup>3/</sup>			
RATING	SYMBOL	VALUE	UNIT
Peak Repetitive Reverse Voltage and DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	400	Volts
Average Rectified Forward Current4/ $T_A = 55^{\circ}C$ (Resistive Load, 60 Hz Sine Wave) $T_A = 100^{\circ}C$	lo	1.00 0.75	Amps
<b>Peak Surge Current</b> <sup>5/</sup> (8.3 ms Pulse, Half Sine Wave, Superimposed on IO, Allow Junction to Reach Equilibrium Between Pulses, per leg)	I <sub>FSM</sub>	20	Amps
Operating and Storage Temperature	T <sub>OP</sub> & T <sub>stg</sub>	-65 to +175	°C
Maximum Thermal Resistance	R <sub>θJC</sub>	13	°C/W

### NOTES:

- 1/ For ordering information, price, operating curves, and availability- Contact factory.
- 2/ Screening based on MIL-PRF-19500. Screening flows available on request.
- 3/ Unless otherwise specified, all maximum ratings/electrical characteristics @25°C.
- 4/ Total current is package dissipation limited to 3A.
- 5/ Surge rating is limited by package.

8 Pin SOIC (SO8)

16 Pin SOIC (SO16)

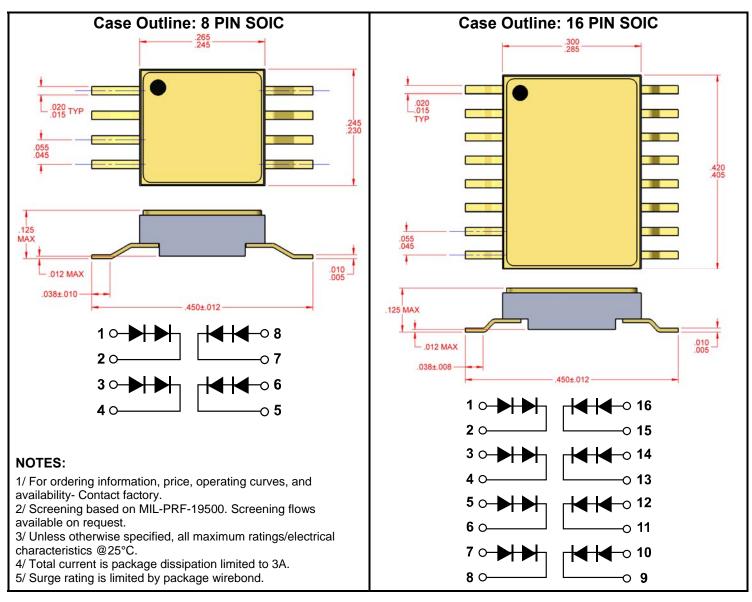




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ELECTRICAL CHARACTERISTICS <sup>3/</sup> CHARACTERISTICS		SYMBOL	Typical	MAX	UNIT
Instantaneous Forward Voltage Drop $(I_F = 1 A_{DC}, 300 \mu sec min pulse)$	$T_A = 25^{\circ}C$ $T_A = 100^{\circ}C$	V <sub>F</sub>	1.7 1.5	2.0 -	V
<b>Reverse Leakage Current</b> (Rated V <sub>R</sub> , 300 μsec min pulse)	$T_A = 25^{\circ}C$ $T_A = 100^{\circ}C$	I <sub>R1</sub> I <sub>R2</sub>	0.3 25	1 50	μA
Junction Capacitance (VR= 5 V)		Cj	10	17	pF
<b>Reverse Recovery Time (Schottky)</b> $(I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A}, I_{RR} = 0.25 \text{ A}, T_A = 25^{\circ}\text{C})$		t <sub>rr</sub>	20	35	nsec



**NOTE:** All specifications are subject to change without notification. SCD's for these devices should be reviewed by SSDI prior to release. **DATA SHEET #: SH0089B** 

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